

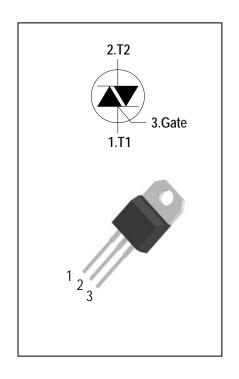
3 Quadrants High temperature Triacs

General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The AIS8CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance atgiven junction temperatures.

Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 8 A)
- ♦ High Commutation dv/dt
- ◆ Isolated heatsink mounted , Isolation Voltage (Viso = 2500V AC)
- High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

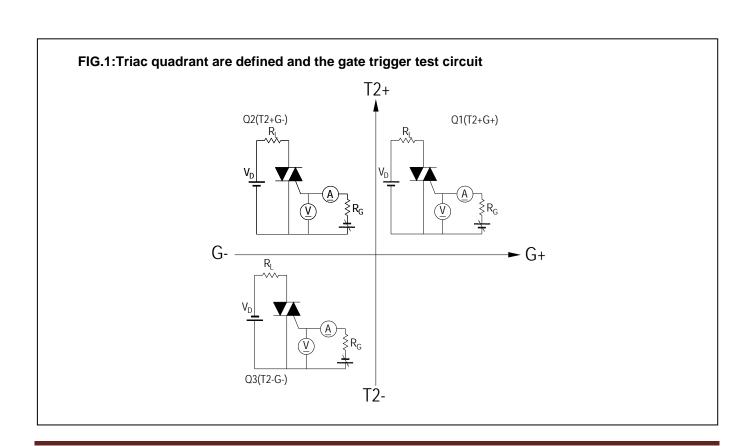
Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Denetitive Deals Off Chate Veltage	T: - 25°C	AIS8CH60	600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	AIS8CH80	800	V
I _{T(RMS)}	R.M.S On-State Current	T _C = 125 °C		8	А
I _{TSM}	Surge On-State Current	Tp=20ms(50Hz)/tp=16.7ms(60Hz)		80/84	А
l ² t	I ² t for fusing	t p=10ms		36	A ² s
-11/-14	Critical rate of rise of on-state F = 120 Hz Tj = 150°C		50	Δ /	
dl/dt	current	$I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$	50	A/µs	
I _{GM}	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 150	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C





Electrical Characteristics(Tj = 25°C unless otherwise specified)

Symbol	Items		Conditions		AIS8CH60/80			Unit
-					S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		V _{DRM} = V _{RRM} , Tj = 25°C		5		uA	
I _{RRM}	Current		V _{DRM} = V _{RRM} , Tj = 150°C	Max.	2.5		mA	
V_{TM}	Peak On-S	tate Voltage	I _{TM} = 11A, t _p = 380 μs	Max.	1.5			V
V_{GD}	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		V	
V_{GT}	Q1-Q2-Q3	Gate Trigger Voltage	Max.		1.5		V	
I _{GT}	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	10	35	50	mA
I _H	Q1-Q2-Q3	Holding Current	I _T = 0.1A	Max.	20	45	60	mA
IL	Q1-Q3	Latching Current	I _G = 1.2 I _{GT}	Max.	20	50	70	mA
	Q2				35	70	100	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	200	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		V_D =400V Tj = 150°C (dl/dt)c=-3.5A/ms	Min.	1	15	20	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	3.7		°C/W		
R _{th(j-a)}	Junction to ambient		Max.	60		°C/W		



ADV

FIG.2: Maximum on-state power dissipation

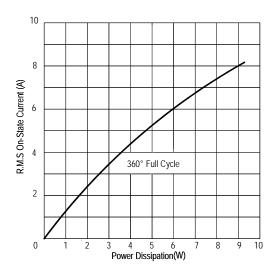


FIG.4: Maximum transient thermal impedance

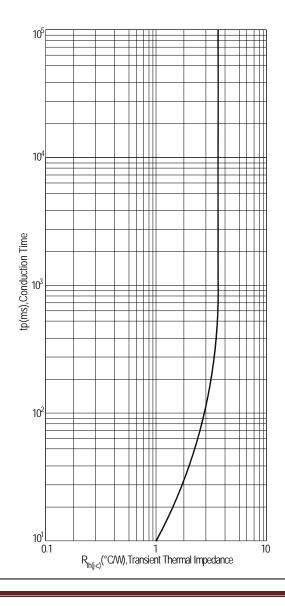


FIG.3: Typical RMS on-state current VS Allowable case Temperature

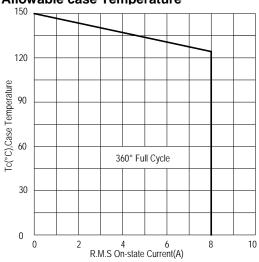


FIG.5: Rated surge on-state current (Non-Repetitive)

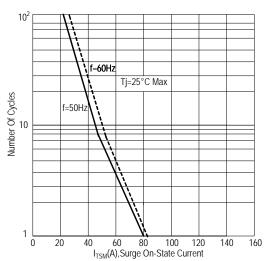


FIG.6: Gate trigger current VS Junction temperature

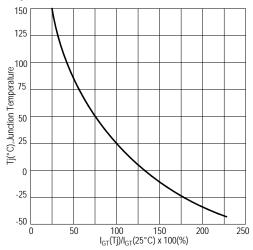




FIG.7:Holding current and Latching current VS Junction temperature

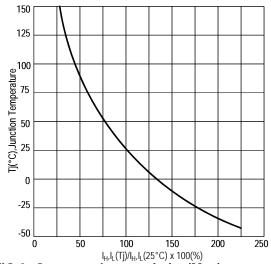
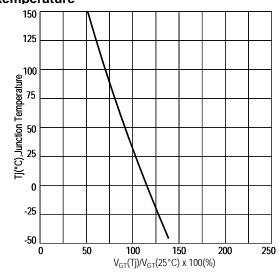
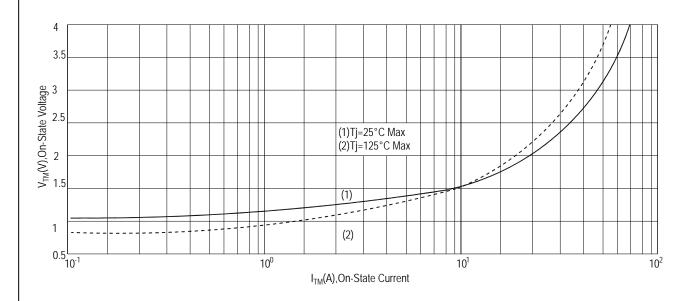


FIG.9: On-state characteristics(Max)

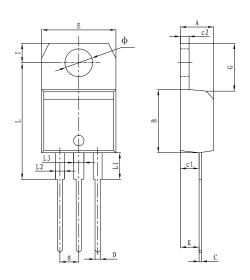
FIG.8: Gate trigger voltage VS Junction temperature





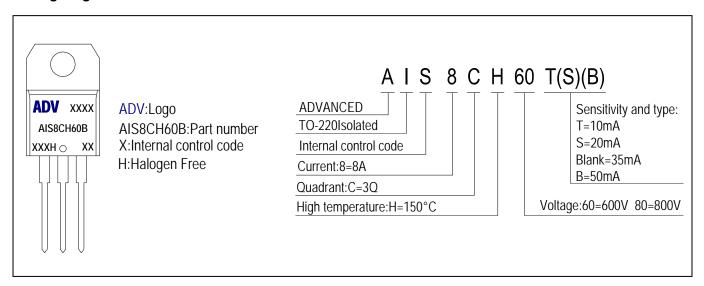


PACKAGE MECHANICAL DATA TO-220(Isolated) Package Dimension



	Dimer	nsions	Dimensions		
Symbol	In Millimeters		In Inches		
	Min	Max	Min	Max	
Α	4.40	4.60	0.173	0.181	
В	9.00	9.30	0.354	0.366	
С	0.40	0.60	0.015	0.023	
c1	2.00	2.60	0.078	0.102	
c2	1.23	1.32	0.048	0.051	
D	0.70	1.00	0.027	0.039	
Е	10.00	10.40	0.393	0.409	
g	2.40	2.70	0.094	0.106	
G	6.20	6.80	0.244	0.267	
ı	2.65	2.95	0.104	0.116	
L	15.80	16.80	0.622	0.661	
L1	3.75		0.147		
L2	1.14	1.70	0.044	0.066	
L3	1.14	1.70	0.044	0.066	
Ф	Ф 3.60 3.90 0.1		0.141	0.153	
К	2.60	TYP	0.102TYP		

Making Diagram



Ordering information

Part number	Package	Marking	Packing	Quantity		
AIS8CH60#	TO-220isolated	AIS8CH60#	Tube	50pcs		
AIS8CH80#	TO-220isolated	AIS8CH80#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



AIS8CH60/80

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